

# Hybrid Membrane development for A MEMS based Stirling engine

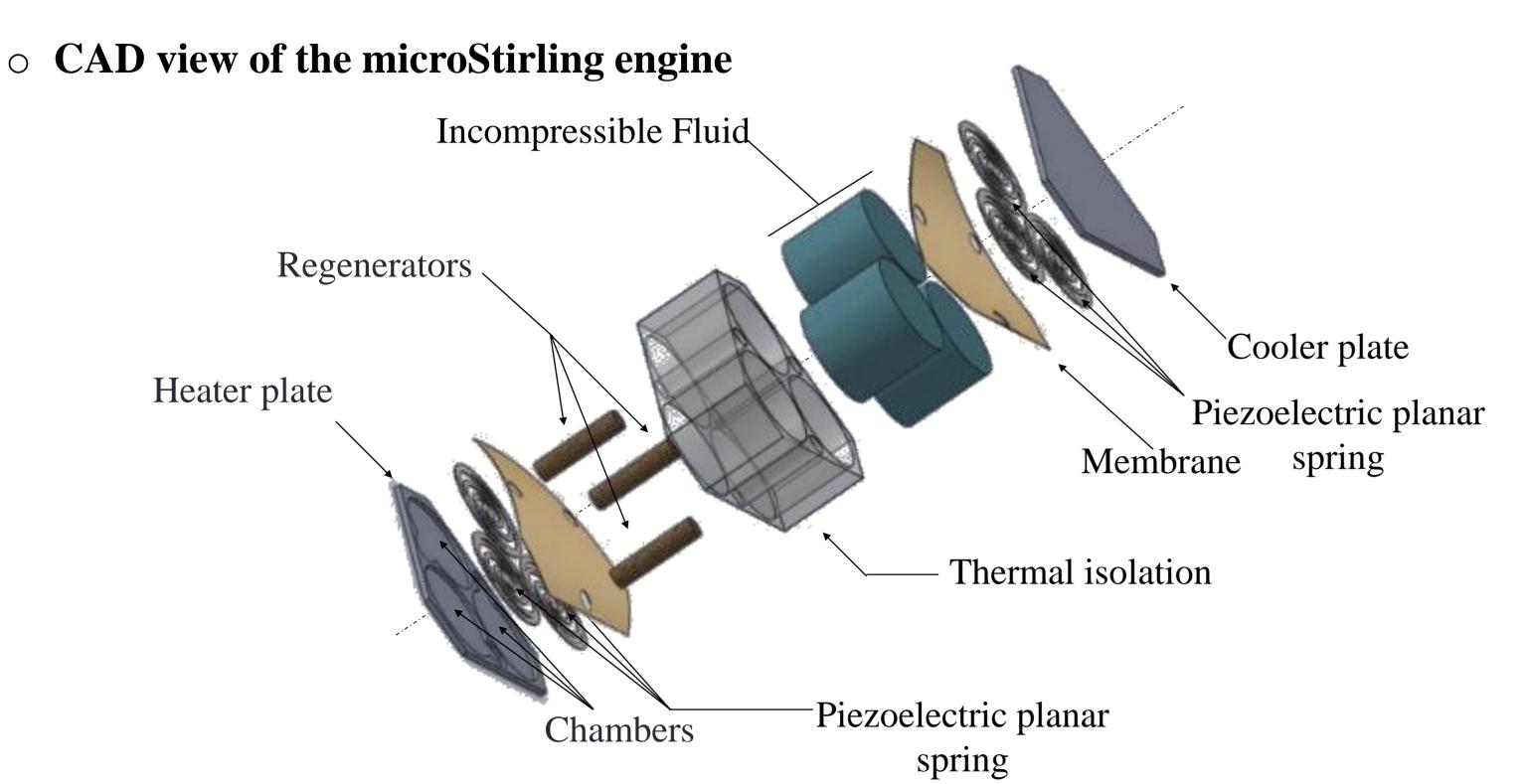
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Abstract: The paper describes the microfabrication of an innovative double acting Stirling engine for low temperature heat recovery. The usual pistons are replaced by hybrid RTV silicone - planar Si spring - fluid diaphragm (HFD). The proposed fabrication process ensures the fabrication of a freely suspended RTV silicone membrane on silicon wafer, the anodic bonding of membrane wafer with glass wafer and the incompressible fluid filling done at the wafer level.

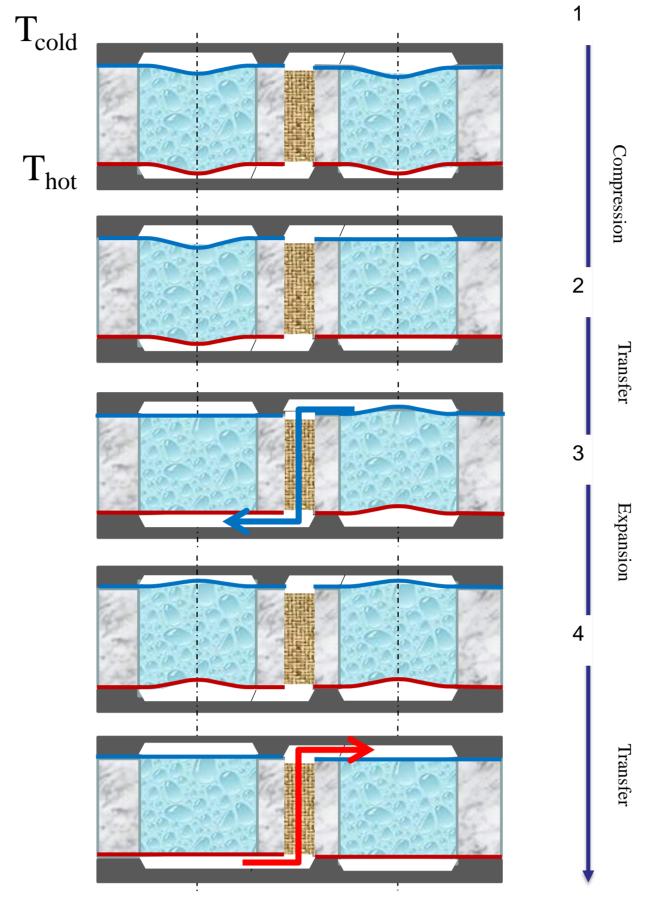
## **GENERAL ARCHITECTURE**

## **WORKING PRINCIPLE**



#### Details of the HFD and technical requirements

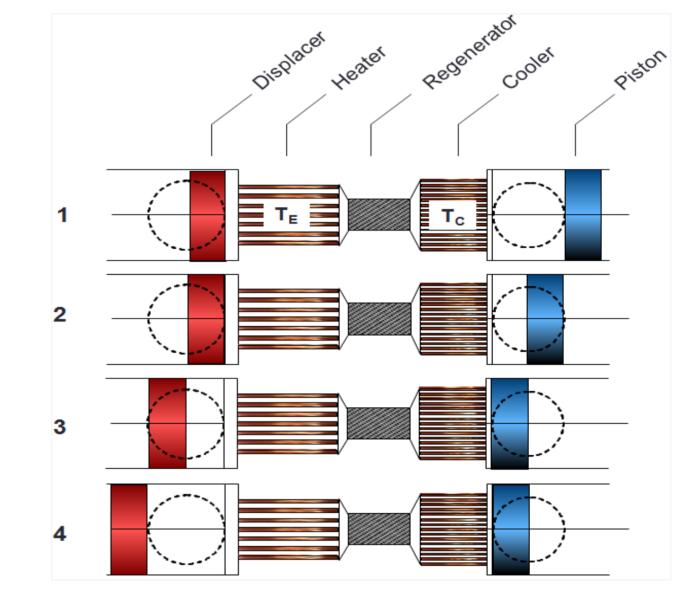
- Chamber diameter :  $\emptyset = 5 \text{ mm}$
- Thin soft membrane ensure gas and fluid filling
- Incompressible fluid (glycerin, vaseline oil) sealing
- No air bubble in chamber filled with fluid to ensure the proper dynamic characteristics
- High quality factor
- Temperature tolerance for anodic bonding  $250 \le T \le 300$  °C (Limited by membrane material)
- Thermal insulation



HFD working Principle

## Ideal Stirling cycle:

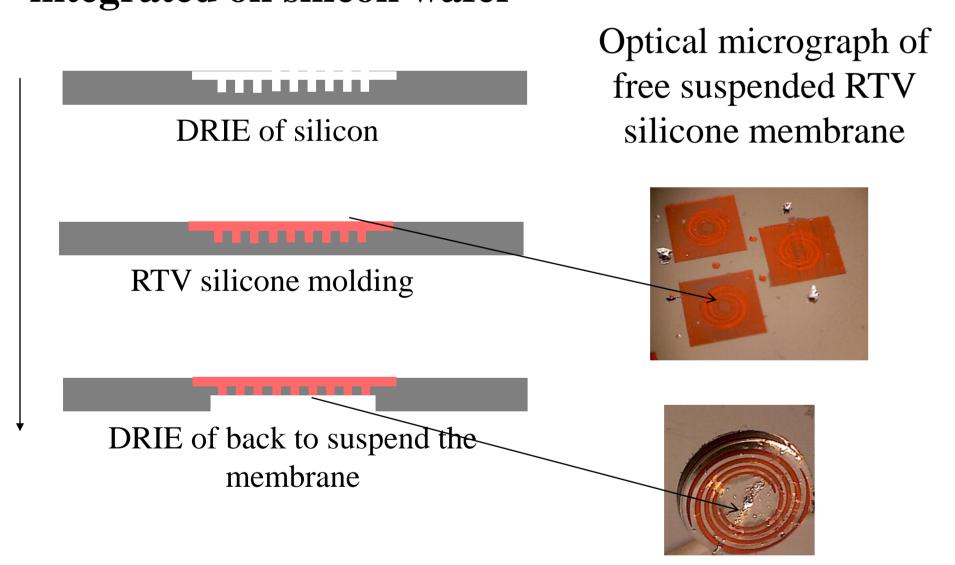
- Isothermal compression and expansion
- Constant volume heating and cooling in the regenerators



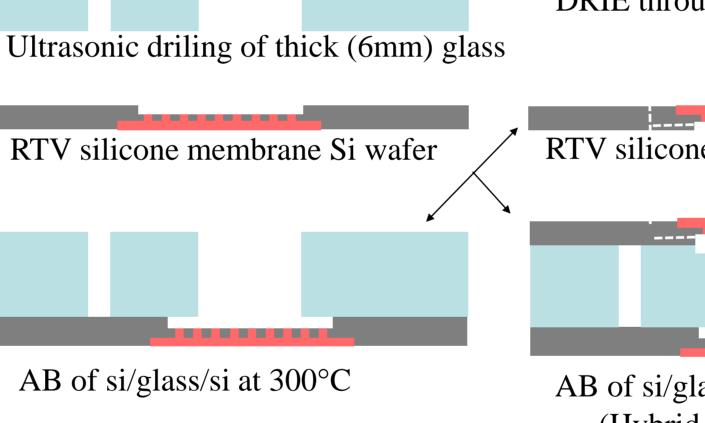
Stirling working Principle

## **MICROFABRICATION**

## I. Microfabricted RTV silicone membrane integrated on silicon wafer



## II. Anodic bonding (AB) of wafers to fabricate HFD



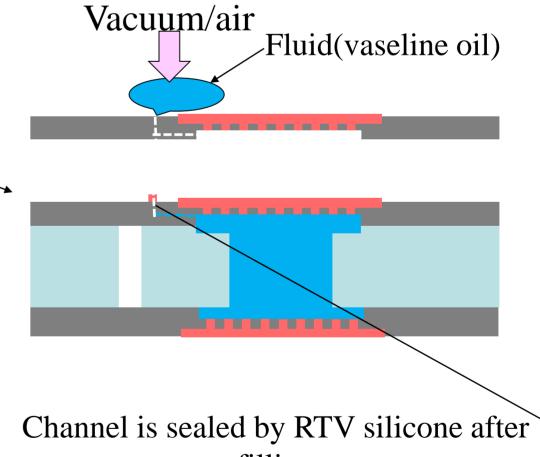
# DRIE through hole in silicon



AB of si/glass/si at 300°C (Hybrid diaphargm)

#### III. Wafer level fluid filling test

Fluid is filled in the cavity with pull-push method by creating a low vacuum followed by venting with nitrogen or air.





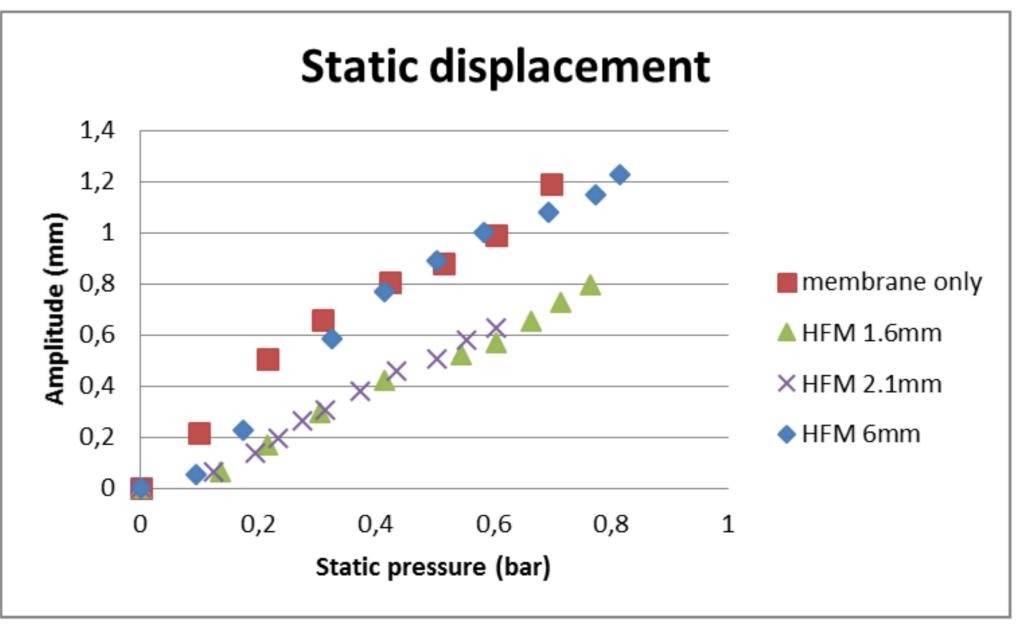
filling

## PRELIMINARY CHARACTERIZATION

## Pull test of low temperature (250°C) anodic bonding and Static displacement measurements

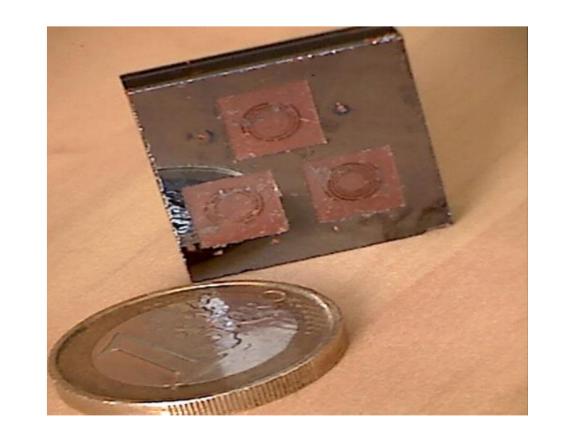
## Pull test result of SI/Glass anodic bonding 350 Force 500 150 100 50 25 30 Area (mm<sup>2</sup>)

Bond strength was measured ~12 MPa which is sufficent for machine hermitical sealing



Static displacement was measured ~0.8mm which is sufficent for piston mode driving membrane

## Microfabricated HFD chip



## Conclusions

- Wafer level fabrication of HFD is successfully demonstrated.
- Multiple anodic bonding is validated and followed by the fabrication of an HFD.
- ✓ The low temperature anodic bonding is validated.

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